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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/763,891	06/11/2001	Takeshi Uchida	566.39787X00	3852
20457	7590 01/05/2004	EXAMINER		
	LI, TERRY, STOUT & K I SEVENTEENTH STREET	UMEZ ERONINI, LYNETTE T		
SUITE 1800	i Sevenieenin Sikeel	ART UNIT	PAPER NUMBER	
ARLINGTON, VA 22209-9889			1765	
			DATE MAILED: 01/05/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

			Application No.	Applicant(s)	i				
Office Action Summary			09/763,891	UCHIDA ET AL.	eV)				
			Examiner	Art Unit					
			Lynette T. Umez-Eronini	1765					
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply									
THE N - Exten after S - If the - If NO - Failur - Any re	DRTENED STATUTORY PERIOD IN AILING DATE OF THIS COMMUN sions of time may be available under the provision SIX (6) MONTHS from the mailing date of this comperiod for reply specified above is less than thirty operiod for reply is specified above, the maximum set to reply within the set or extended period for reply preceived by the Office later than three months of patent term adjustment. See 37 CFR 1.704(b).	NICATION. us of 37 CFR 1.13 umunication. (30) days, a reply statutory period w. ly will, by statute,	6(a). In no event, however, may a reply be tir within the statutory minimum of thirty (30) day ill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	mely filed /s will be considered timely. the mailing date of this coming (35 U.S.C. § 133).	munication.				
1)⊠	Responsive to communication(s) file	ed on <u>08 S</u> e	ptember 2003.						
			action is non-final.	·					
Disposition	on of Claims								
4)🖂	Claim(s) 1-51 is/are pending in the	application.							
	4a) Of the above claim(s) <u>11-15 and</u>	<u>d 23-33</u> is/ar	e withdrawn from consideration.						
5)🖂	Claim(s) <u>1-10,16-22 and 34-41</u> is/a	re allowed.	•						
6)⊠	Claim(s) <u>42-51</u> is/are rejected.				· · ·				
7:)	Claim(s) is/are objected to.								
8)[Claim(s) are subject to restr	iction and/or	election requirement.						
Application	on Papers								
9)[7	The specification is objected to by t	ne Examiner		7	: · · · · · · · · · · · · · · · · · · ·				
10) 🔲 🗆	The drawing(s) filed on is/are	e: a) 🗌 acce	pted or b) objected to by the	Examiner.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).									
	Replacement drawing sheet(s) including	g the correction	on is required if the drawing(s) is ob	jected to. See 37 CFR	1.121(d).				
11) 🔲 🗆	The oath or declaration is objected	to by the Exa	aminer. Note the attached Office	Action or form PTO	-152.				
Priority u	nder 35 U.S.C. §§ 119 and 120		A Section of the Contract of t	* * 1					
a)[Acknowledgment is made of a clair All b) Some * c) None of: Certified copies of the priority Copies of the certified copies application from the Internati	y documents y documents s of the priori	have been received. have been received in Applicative documents have been received.	ion No	age				
13)□ A sii 37 a) 14)□ A	ee the attached detailed Office acti cknowledgment is made of a claim nce a specific reference was include CFR 1.78. The translation of the foreign lacknowledgment is made of a claim	on for a list of for domesticed in the first anguage provious for domestic	of the certified copies not received priority under 35 U.S.C. § 119(of the specification of t	e) (to a provisional a r in an Application Da ceived.) and/or 121 since a	ata Sheet. specific				
; re	ference was included in the first se	ntence of the	e specification or in an Application	on Data Sheet. 37 Cl	-K 1./8.				
2) Notice	(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (nation Disclosure Statement(s) (PTO-1449)		5) Notice of Informal F	r (PTO-413) Paper No(s). Patent Application (PTO-1					

DETAILED ACTION

Oath/Declaration

1. The affidavit under 37 CFR 1.132 filed 9/8/2003 is sufficient to overcome the rejection of claims 1-10, 16-22, respectively as based upon the and 103 rejection of the claims.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

3. Claims 42-48 and 50 are rejected under 35 U.S.C. 102(b) as being anticipated by Luo et al (CMP-MIC conference 1996 ISMIC –100P/96/0145).

Luo teaches, "The chemical-mechanical polishing (CMP) of copper was conducted with ferric nitrate. . . and 1H-benzotiazole (BTA) . . . A surfactant, poly (ethylene glycol) . . . was employed to stabilize the polishing slurry" (page 1450. The aforementioned reads on,

A polishing solution for a metal, comprising:

a first protective-film which is a compound; and

Application/Control Number: 09/763,891

Art Unit: 1765

a second protective-film forming agent.

Since Luo uses a polishing solution that comprises the same chemicals, which are used to polish the same material as in the claimed invention, then using Luo's first protective-film forming agent in the same manner as the claimed invention would inherently result in a compound capable of forming a protective film by physically adsorbing the first protective film forming agent with the metal film surface; then using Luo's second protective-film forming agent in the same manner as the claimed invention would inherently result in a compound which assists the first protective-film forming agent in forming a protective film; and using Luo's polishing solution in the same manner as the claimed invention would inherently result in having a chemical mechanical polishing rate of the metal of at least 100 nm/minute and an etching rate of the metal of at most 10 nm/minute, in claim 42, wherein said etching rate is 1 nm/minute or lower, in claim 44; wherein said chemical mechanical polishing rate is 250 nm/minute or higher, in claim 45;

The said aforementioned further reads on.

The solution consisting essentially of said first protective-film forming agent and said second protective-film forming agent, in claim 43;

wherein said first-protective agent is at least one selected from the group consisting of azoles, in claim 44; and benzotriazole, in claim 47;

wherein said second protective-film forming agent is a compound having vinyl polymer, in claim 48; and

wherein said metal contains at least one selected from the group consisting of copper, in claim 50.

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).
- 6. Claim 49 is rejected under 35 U.S.C. 103(a) as being unpatentable over Luo (CMP-MIC) as applied to claim 42 above, and further in view of Ronay (US 5,876,490).

Luo differs in failing to specify compounds that are second protective-film forming agents as recited in claim 49.

Art Unit: 1765

Ronay teaches a slurry that comprises a abrasive particles and polyelectrolyte (polyions), (column 4, lines 55-56), which can be bound to the polishing abrasive particles, which includes acidic groups such as poly(acrylic acids) (column 5, lines 26-31) and which is the same as applicant's second protective-film forming agent.

It is the examiner's position that it would have been obvious to one having ordinary skill in the art at the time of the claimed invention to modify Luo by using the second protective-film forming agent as taught by Ronay for the purpose of improving planarization (column 6, line 67 - column 7, line 3).

7. Claim 51 is rejected under 35 U.S.C. 103(a) as being unpatentable over Luo (CMP-MIC) as applied to claim 42 above, and further in view of Hayashi et al. (IDEM, 1992).

Luo differs in failing to teach the polishing solution for the metal, which substantially does not contain any abrasive grains.

Hayashi teaches an abrasive-free, chemical-mechanical-polishing technique in which aqueous amine and hydrogen peroxide solution is used as a polishing liquid (p. 976, 1st paragraph).

It is the examiner's position to modify Luo by using an abrasive free polishing liquid as taught by Hayashi for the purpose of minimizing scratches of the polished surface.

Application/Control Number: 09/763,891

Art Unit: 1765

Allowable Subject Matter

Page 6

8. Claims 1-10, 16-22, and 34-41 are allowed.

9. The following is a statement of reasons for the indication of allowable subject

matter: Applicants' affidavit has provided experimental results (see pages 2-6), which

show that glycine and/or an amidosulfuric acid fail to qualify as a second protective-film

forming agent as in the present invention and which achieved an unexpectedly greater

polishing rate and unexpectedly lower etching rate by using the solution of Example 7 of

the present invention when compared to using Sasaki's (in US Patent 5,779,095)

polishing solution.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Lynette T. Umez-Eronini whose telephone number is

571-272-1470. The examiner is normally unavailable on the First Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Nadine Norton can be reached on 571-272-1435. The fax phone numbers

for the organization where this application or proceeding is assigned are for regular 571-

273-0223.

Lynette J. Umez Econini

December 29, 2003